Low-power dual inverting buffer/line driver; 3-state

Rev. 9 — 19 March 2019

Product data sheet

1. General description

The 74AUP2G240 provides the dual inverting buffer/line driver with 3-state output. The 3-state output is controlled by the output enable input ($n\overline{OE}$). A HIGH level at pin $n\overline{OE}$ causes the output to assume a high-impedance OFF-state.

Schmitt-trigger action at all inputs makes the circuit tolerant to slower input rise and fall times across the entire V_{CC} range from 0.8 V to 3.6 V.

This device ensures a very low static and dynamic power consumption across the entire V_{CC} range from 0.8 V to 3.6 V.

This device is fully specified for partial Power-down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

This device has the input-disable feature, which allows floating input signals. The inputs are disabled when the output enable input $n\overline{OE}$ is HIGH.

2. Features and benefits

- Wide supply voltage range from 0.8 V to 3.6 V
- High noise immunity
- Complies with JEDEC standards:
 - JESD8-12 (0.8 V to 1.3 V)
 - JESD8-11 (0.9 V to 1.65 V)
 - JESD8-7 (1.2 V to 1.95 V)
 - JESD8-5 (1.8 V to 2.7 V)
 - JESD8-B (2.7 V to 3.6 V)
- ESD protection:
 - HBM JESD22-A114F Class 3A exceeds 5000 V
 - MM JESD22-A115-A exceeds 200 V
 - CDM JESD22-C101E exceeds 1000 V
- Low static power consumption; $I_{CC} = 0.9 \mu A$ (maximum)
- Latch-up performance exceeds 100 mA per JESD78 Class II
- Inputs accept voltages up to 3.6 V
- Low-noise overshoot and undershoot < 10 % of V_{CC}
- Input-disable feature allows floating input conditions
- IOFF circuitry provides partial Power-down mode operation
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

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3. Ordering information

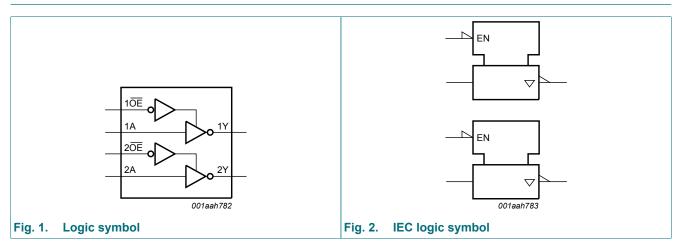
Type number	Package								
	Temperature range	Name	Description	Version					
74AUP2G240DC	-40 °C to +125 °C	VSSOP8	plastic very thin shrink small outline package; 8 leads; body width 2.3 mm	SOT765-1					
74AUP2G240GT	-40 °C to +125 °C	XSON8	plastic extremely thin small outline package; no leads; 8 terminals; body 1 × 1.95 × 0.5 mm	SOT833-1					
74AUP2G240GF	-40 °C to +125 °C	XSON8	extremely thin small outline package; no leads; 8 terminals; body 1.35 × 1 × 0.5 mm	SOT1089					
74AUP2G240GM	-40 °C to +125 °C	XQFN8	plastic, extremely thin quad flat package; no leads; 8 terminals; body 1.6 × 1.6 × 0.5 mm	SOT902-2					
74AUP2G240GN	-40 °C to +125 °C	XSON8	extremely thin small outline package; no leads; 8 terminals; body 1.2 × 1.0 × 0.35 mm	SOT1116					
74AUP2G240GS	-40 °C to +125 °C	XSON8	extremely thin small outline package; no leads; 8 terminals; body 1.35 × 1.0 × 0.35 mm	SOT1203					

4. Marking

Table 2. Marking codes					
Type number	Marking code [1]				
74AUP2G240DC	p40				
74AUP2G240GT	p40				
74AUP2G240GF	p2				
74AUP2G240GM	p40				
74AUP2G240GN	p2				
74AUP2G240GS	p2				

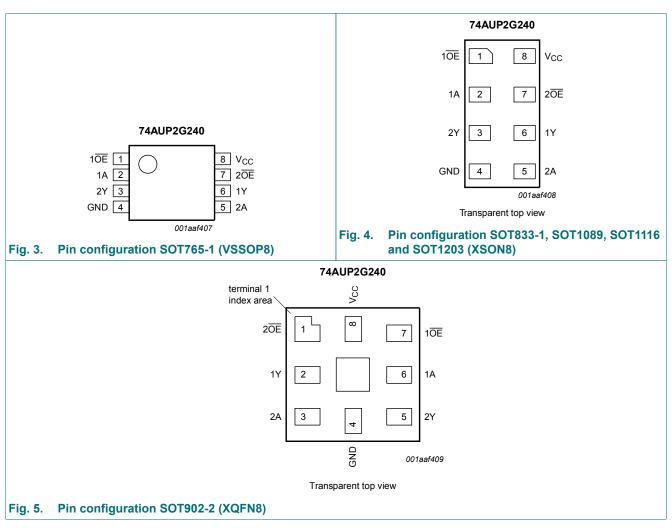
[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

5. Functional diagram



74AUP2G240

6. Pinning information



6.1. Pinning

6.2. Pin description

Table 3. Pin description

Symbol	Pin	Description		
	SOT765-1, SOT833-1, SOT1089, SOT1116 and SOT1203	SOT902-2		
1 <u>0E, 20E</u>	1, 7	7, 1	output enable input (active LOW)	
1A, 2A	2, 5	6, 3	data input	
GND	4	4	ground (0 V)	
1Y, 2Y	6, 3	2, 5	data output	
V _{CC}	8	8	supply voltage	

7. Functional description

Table 4. Function table

H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = high-impedance OFF-state.

Input nOE		Output
nOE	nA	nY
L	L	Н
L	Н	L
Н	X	Z

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+4.6	V
I _{IK}	input clamping current	V _I < 0 V	-50	-	mA
VI	input voltage	[1]	-0.5	+4.6	V
I _{OK}	output clamping current	V _O < 0 V	-50	-	mA
Vo	output voltage	Active mode and Power-down mode [1]	-0.5	+4.6	V
I _O	output current	$V_{O} = 0 V \text{ to } V_{CC}$	-	±20	mA
I _{CC}	supply current		-	50	mA
I _{GND}	ground current		-50	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	T _{amb} = -40 °C to +125 °C [2]	-	250	mW

[1] The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For VSSOP8 packages: above 110 °C the value of Ptot derates linearly with 8.0 mW/K.

For XSON8 and XQFN8 packages: above 118 °C the value of Ptot derates linearly with 7.8 mW/K.

9. Recommended operating conditions

Table 6. Operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		0.8	3.6	V
VI	input voltage		0	3.6	V
Vo	output voltage	Active mode	0	V _{CC}	V
		Power-down mode; V _{CC} = 0 V	0	3.6	V
T _{amb}	ambient temperature		-40	+125	°C
Δt/ΔV	input transition rise and fall rate	V _{CC} = 0.8 V to 3.6 V	0	200	ns/V

10. Static characteristics

Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 2	5 °C					
VIH	HIGH-level input	V _{CC} = 0.8 V	0.70V _{CC}	-	-	V
	voltage	V _{CC} = 0.9 V to 1.95 V	0.65V _{CC}	-	-	V
		V _{CC} = 2.3 V to 2.7 V	1.6	-	-	V
		V _{CC} = 3.0 V to 3.6 V	SV $0.70V_{CC}$ - - V 9V to 1.95 V $0.65V_{CC}$ - - V 9V to 2.7 V 1.6 - - V 9V to 3.6 V 2.0 - - V 9V to 1.95 V - 0.30V _{CC} V 9V to 1.95 V - 0.35V _{CC} V 9V to 2.7 V - 0.35V _{CC} V 9V to 2.7 V - 0.35V _{CC} V 9V to 3.6 V - 0.7 V 9V to 3.6 V - 0.9 V 11 mA; V _{CC} = 0.8 V to 3.6 V V _{CC} - 0.1 - V 1.1 mA; V _{CC} = 1.1 V 0.75V _{CC} - - V 1.32 - V - - V 2.3 mA; V _{CC} = 2.3 V 1.9 - - V 2.7 mA; V _{CC} = 3.0 V 2.72 - V V 0 µA; V _{CC} = 0.8 V to 3.6 V - - 0.31 V 0 9 mA; V _{CC}	V		
V _{IL}	LOW-level input	V _{CC} = 0.8 V	-	-	0.30V _{CC}	V
V	voltage	V _{CC} = 0.9 V to 1.95 V	-	-	0.35V _{CC}	V
		V _{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		V _{CC} = 3.0 V to 3.6 V	-	-	0.9	V
V _{OH}	HIGH-level output	$V_{I} = V_{IH} \text{ or } V_{IL}$				
	voltage	I_{O} = -20 µA; V_{CC} = 0.8 V to 3.6 V	V _{CC} - 0.1	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.75V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	1.11	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.32	-	-	V
		I _O = -2.3 mA; V _{CC} = 2.3 V	2.05	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.9	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.72	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.6	-	-	V
V _{OL}	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
0L		$I_{O} = 20 \ \mu\text{A}; \ V_{CC} = 0.8 \ \text{V} \text{ to } 3.6 \ \text{V}$	-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.3V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.31	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.31	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.31	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.44	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.31	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.44	V
I _I	input leakage current	V_1 = GND to 3.6 V; V_{CC} = 0 V to 3.6 V	-	-	±0.1	μA
I _{OZ}	OFF-state output current	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{O} = 0 \text{ V to } 3.6 \text{ V};$ $V_{CC} = 0 \text{ V to } 3.6 \text{ V}$	-	-	±0.1	μA
I _{OFF}	power-off leakage current	V_{I} or V_{O} = 0 V to 3.6 V; V_{CC} = 0 V	-	-	±0.2	μA
Δl _{OFF}	additional power-off leakage current	V_{I} or V_{O} = 0 V to 3.6 V; V_{CC} = 0 V to 0.2 V	-	-	±0.2	μA
I _{CC}	supply current	V_I = GND or V_{CC} ; I_O = 0 A; V_{CC} = 0.8 V to 3.6 V	-	-	0.5	μA
Δl _{CC}	additional supply current	data input; V _I = V _{CC} - 0.6 V; I _O = 0 A; V _{CC} = 3.3 V	[1] -	-	40	μA
			[1] -	-	110	μA
		disabled inputs; V_I = GND to 3.6 V; nOE = V _{CC} ; V _{CC} = 0.8 V to 3.6 V	-	-	1	μA

Low-power dua	l inverting	buffer/line	driver; 3-state
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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
CI	input capacitance	V_{CC} = 0 V to 3.6 V; V _I = GND or V _{CC}	-	0.6	-	pF
Co	output capacitance	output enabled; V_0 = GND; V_{CC} = 0 V	-	1.7	-	pF
		output disabled; V_{CC} = 0 V to 3.6 V; V_O = GND or V_{CC}	-	1.5	-	pF
T _{amb} = -4	40 °C to +85 °C		I			
V _{IH}	HIGH-level input	V _{CC} = 0.8 V	0.70V _{CC}	-	-	V
	voltage	V _{CC} = 0.9 V to 1.95 V	0.65V _{CC}	-	-	V
		V _{CC} = 2.3 V to 2.7 V	1.6	-	-	V
		V _{CC} = 3.0 V to 3.6 V	2.0	-	-	V
V _{IL}	LOW-level input	V _{CC} = 0.8 V	-	-	0.30V _{CC}	V
	voltage	V _{CC} = 0.9 V to 1.95 V	-	-	0.35V _{CC}	V
		V _{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		V _{CC} = 3.0 V to 3.6 V	-	-	0.9	V
V _{OH}	HIGH-level output	V _I = V _{IH} or V _{IL}				
	voltage	I_{O} = -20 µA; V_{CC} = 0.8 V to 3.6 V	V _{CC} - 0.1	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.7V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	1.03	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.30	-	-	V
		I _O = -2.3 mA; V _{CC} = 2.3 V	1.97	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.85	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.67	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.55	-	-	V
V _{OL}	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		I_{O} = 20 µA; V_{CC} = 0.8 V to 3.6 V	-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.3V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.37	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.35	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.33	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.45	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.33	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.45	V
I _I	input leakage current	V_1 = GND to 3.6 V; V_{CC} = 0 V to 3.6 V	-	-	±0.5	μA
I _{OZ}	OFF-state output current	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{O} = 0 \text{ V to } 3.6 \text{ V};$ $V_{CC} = 0 \text{ V to } 3.6 \text{ V}$	-	-	±0.5	μA
I _{OFF}	power-off leakage current	V_{I} or V_{O} = 0 V to 3.6 V; V_{CC} = 0 V	-	-	±0.5	μA
ΔI _{OFF}	additional power-off leakage current	V_{I} or V_{O} = 0 V to 3.6 V; V_{CC} = 0 V to 0.2 V	-	-	±0.6	μA
I _{CC}	supply current	$V_I = GND \text{ or } V_{CC}; I_O = 0 \text{ A};$ $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	0.9	μA
ΔI _{CC}	additional supply current	data input; V _I = V _{CC} - 0.6 V; I _O = 0 A; V _{CC} = 3.3 V	[1] -	-	50	μA
		$\overline{\text{NOE}}$ input; V _I = V _{CC} - 0.6 V; I _O = 0 A; V _{CC} = 3.3 V	[1] -	-	120	μA
		disabled inputs; V_I = GND to 3.6 V; nOE = V _{CC} ; V _{CC} = 0.8 V to 3.6 V	-	-	1	μA

Symbo	I Parameter	Conditions		Min	Тур	Max	Unit
T _{amb} =	-40 °C to +125 °C						
VIH	HIGH-level input	V _{CC} = 0.8 V		0.75V _{CC}	-	-	V
	voltage	V _{CC} = 0.9 V to 1.95 V		0.70V _{CC}	-	-	V
		V _{CC} = 2.3 V to 2.7 V		1.6	-	-	V
		V _{CC} = 3.0 V to 3.6 V		2.0	-	-	V
V _{IL}	LOW-level input	V _{CC} = 0.8 V		-	-	0.25V _{CC}	V
	voltage	V _{CC} = 0.9 V to 1.95 V		-	-	0.30V _{CC}	V
		V _{CC} = 2.3 V to 2.7 V		-	-	0.7	V
		V _{CC} = 3.0 V to 3.6 V		-	-	0.9	V
V _{OH}	HIGH-level output	$V_{I} = V_{IH} \text{ or } V_{IL}$					
	voltage	I_{O} = -20 µA; V _{CC} = 0.8 V to 3.6 V		V _{CC} - 0.11	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V		0.6V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V		0.93	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V		1.17	-	-	V
		I _O = -2.3 mA; V _{CC} = 2.3 V		1.77	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V		1.67	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V		2.40	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V		2.30	-	-	V
V _{OL}	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$					-
		I_{O} = 20 µA; V_{CC} = 0.8 V to 3.6 V		-	-	0.11	V
		I _O = 1.1 mA; V _{CC} = 1.1 V		-	-	0.33V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V		-	-	0.41	V
		I _O = 1.9 mA; V _{CC} = 1.65 V		-	-	0.39	V
		I _O = 2.3 mA; V _{CC} = 2.3 V		-	-	0.36	V
		I _O = 3.1 mA; V _{CC} = 2.3 V		-	-	0.50	V
		I _O = 2.7 mA; V _{CC} = 3.0 V		-	-	0.36	V
		I _O = 4.0 mA; V _{CC} = 3.0 V		-	-	0.50	V
l _l	input leakage current	V_1 = GND to 3.6 V; V_{CC} = 0 V to 3.6 V		-	-	±0.75	μA
I _{OZ}	OFF-state output current	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{O} = 0 \text{ V to } 3.6 \text{ V};$ $V_{CC} = 0 \text{ V to } 3.6 \text{ V}$		-	-	±0.75	μA
I _{OFF}	power-off leakage current	$V_{\rm I} \text{ or } V_{\rm O} = 0 \text{ V to } 3.6 \text{ V}; V_{\rm CC} = 0 \text{ V}$		-	-	±0.75	μA
∆I _{OFF}	additional power-off leakage current	V_{I} or V_{O} = 0 V to 3.6 V; V_{CC} = 0 V to 0.2 V		-	-	±0.75	μA
I _{CC}	supply current	$V_{I} = GND \text{ or } V_{CC}; I_{O} = 0 \text{ A};$ $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$		-	-	1.4	μA
∆I _{CC}	additional supply current	data input; V _I = V _{CC} - 0.6 V; I _O = 0 A; V _{CC} = 3.3 V	[1]	-	-	75	μA
		$\overline{\text{NOE}}$ input; V _I = V _{CC} - 0.6 V; I _O = 0 A; V _{CC} = 3.3 V	[1]	-	-	180	μA
		disabled inputs; V_1 = GND to 3.6 V; n \overline{OE} = V _{CC} ; V _{CC} = 0.8 V to 3.6 V		-	-	1	μA

[1] One input at V_{CC} - 0.6 V, other input at V_{CC} or GND.

11. Dynamic characteristics

Table 8. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V; for test circuit see Fig. 8.

Symbol	Parameter	Conditions		25 °C		-40 °C to +125 °C			Unit
				Тур <mark>[1]</mark>	Max	Min	Max (85 °C)	Max (125 °C)	
C _L = 5 p	F								
t _{pd}	propagation	nA to nY; see Fig. 6 [2]							
	delay	V _{CC} = 0.8 V	-	22.3	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.0	5.8	12.6	2.8	14.1	15.5	ns
		V _{CC} = 1.4 V to 1.6 V	2.3	4.0	7.3	2.1	8.5	9.4	ns
		V _{CC} = 1.65 V to 1.95 V	2.0	3.2	5.5	1.9	6.7	7.4	ns
		V_{CC} = 2.3 V to 2.7 V	1.8	2.6	4.1	1.5	4.8	5.3	ns
		V _{CC} = 3.0 V to 3.6 V	1.4	2.3	3.6	1.3	4.1	4.6	ns
t _{en}	enable time	nOE to nY; see Fig. 7 [3]							
		V _{CC} = 0.8 V	-	70.2	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.1	6.4	14.3	2.8	15.9	17.5	ns
		V _{CC} = 1.4 V to 1.6 V	2.5	4.4	8.1	2.2	9.5	10.5	ns
		V _{CC} = 1.65 V to 1.95 V	2.1	3.6	6.2	1.9	7.4	8.2	ns
		V _{CC} = 2.3 V to 2.7 V	1.8	2.8	4.6	1.7	5.4	6.0	ns
		V _{CC} = 3.0 V to 3.6 V	1.7	2.5	4.0	1.7	4.7	5.3	ns
t _{dis}	disable time	nOE to nY; see Fig. 7 [4]							
		V _{CC} = 0.8 V	-	14.8	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	2.0	4.3	7.4	2.3	8.3	9.2	ns
		V _{CC} = 1.4 V to 1.6 V	1.6	3.2	5.2	1.7	5.9	6.5	ns
		V _{CC} = 1.65 V to 1.95 V	1.5	3.0	4.8	1.5	5.5	6.1	ns
		V _{CC} = 2.3 V to 2.7 V	1.1	2.2	3.5	1.4	4.0	4.5	ns
		V _{CC} = 3.0 V to 3.6 V	1.3	2.5	3.9	1.4	4.5	5.0	ns
C _L = 10	pF								
t _{pd}	propagation	nA to nY; see Fig. 6 [2]							
	delay	V _{CC} = 0.8 V	-	25.7	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.5	6.6	14.5	3.2	16.3	18.0	ns
		V _{CC} = 1.4 V to 1.6 V	2.2	4.6	8.4	2.0	9.9	10.9	ns
		V _{CC} = 1.65 V to 1.95 V	2.0	3.8	6.4	1.8	7.7	8.6	ns
		V _{CC} = 2.3 V to 2.7 V	1.8	3.1	4.8	1.7	5.7	6.4	ns
		V _{CC} = 3.0 V to 3.6 V	1.7	2.8	4.3	1.7	5.0	5.5	ns
t _{en}	enable time	nOE to nY; see Fig. 7 [3]							
		V _{CC} = 0.8 V	-	74.0	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.6	7.4	16.3	3.2	18.2	20.1	ns
		V _{CC} = 1.4 V to 1.6 V	2.3	5.1	9.2	2.1	10.9	12.0	ns
		V _{CC} = 1.65 V to 1.95 V	2.0	4.1	7.1	1.8	8.5	9.4	ns
		V _{CC} = 2.3 V to 2.7 V	1.8	3.4	5.4	1.7	6.4	7.1	ns
		V _{CC} = 3.0 V to 3.6 V	1.8	3.1	4.8	1.7	5.7	6.3	ns

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Low-power dual inverting buffer/line driver; 3-state

Symbol	Parameter	Conditions		25 °C		-40 °C to +125 °C			Unit
				Min Typ [1]		Min	Max (85 °C)	Max (125 °C)	
t _{dis}	disable time	nOE to nY; see Fig. 7 [4]							
		V _{CC} = 0.8 V	-	33.7	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.4	5.4	9.0	3.2	10.0	11.0	ns
		V _{CC} = 1.4 V to 1.6 V	2.1	4.1	6.3	2.1	7.1	7.9	ns
		V _{CC} = 1.65 V to 1.95 V	2.3	4.2	6.3	1.8	7.1	7.9	ns
		V _{CC} = 2.3 V to 2.7 V	1.6	3.0	4.6	1.7	5.2	5.7	ns
		V _{CC} = 3.0 V to 3.6 V	2.1	3.8	5.7	1.7	6.4	7.1	ns
C _L = 15	pF	· · · · · · · · · · · · · · · · · · ·							
t _{pd}	propagation	nA to nY; see Fig. 6 [2]							
	delay	V _{CC} = 0.8 V	-	29.0	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.9	7.4	16.3	3.6	18.4	20.2	ns
		V _{CC} = 1.4 V to 1.6 V	3.0	5.1	9.4	2.5	11.1	12.3	ns
		V _{CC} = 1.65 V to 1.95 V	2.2	4.2	7.2	2.1	8.7	9.6	ns
		V _{CC} = 2.3 V to 2.7 V	2.0	3.5	5.4	1.9	6.5	7.2	ns
		V _{CC} = 3.0 V to 3.6 V	2.0	3.3	4.9	1.9	5.7	6.4	ns
t _{en}	enable time	$n\overline{OE}$ to nY; see <u>Fig. 7</u> [3]							
		V _{CC} = 0.8 V	-	77.8	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	4.0	8.2	18.2	3.6	20.4	22.5	ns
		V _{CC} = 1.4 V to 1.6 V	3.0	5.6	10.3	2.5	12.2	13.4	ns
		V _{CC} = 1.65 V to 1.95 V	2.3	4.6	7.9	2.1	9.5	10.5	ns
		V _{CC} = 2.3 V to 2.7 V	2.1	3.9	6.0	2.0	7.2	7.9	ns
		V _{CC} = 3.0 V to 3.6 V	2.1	3.6	5.5	1.9	6.4	7.1	ns
t _{dis}	disable time	$n\overline{OE}$ to nY; see <u>Fig. 7</u> [4]							
		V _{CC} = 0.8 V	-	62.5	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	4.3	6.6	10.4	3.6	11.6	12.8	ns
		V _{CC} = 1.4 V to 1.6 V	3.0	5.0	7.4	2.5	8.4	9.3	ns
		V _{CC} = 1.65 V to 1.95 V	3.0	5.3	7.8	2.1	8.7	9.7	ns
		V _{CC} = 2.3 V to 2.7 V	2.1	3.8	5.7	2.0	6.4	7.1	ns
		V _{CC} = 3.0 V to 3.6 V	2.9	5.0	7.4	1.9	8.3	9.1	ns
C _L = 30	pF					1			
t _{pd}	propagation	nA to nY; see Fig. 6 [2]							
-	delay	V _{CC} = 0.8 V	-	39.1	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	5.0	9.7	21.6	4.6	24.3	26.8	ns
		V _{CC} = 1.4 V to 1.6 V	4.0	6.7	12.3	3.0	14.6	16.1	ns
		V _{CC} = 1.65 V to 1.95 V	2.9	5.5	9.5	2.7	11.5	12.6	ns
		V _{CC} = 2.3 V to 2.7 V	2.7	4.6	7.1	2.5	8.6	9.5	ns
		V _{CC} = 3.0 V to 3.6 V	2.6	4.3	6.4	2.5	7.7	8.5	ns

Symbol	Parameter	Conditions	25 °C			-40 °C to +125 °C			Unit
			Min	Typ [1]	Мах	Min	Max (85 °C)	Max (125 °C)	
t _{en}	enable time	nOE to nY; see Fig. 7 [3]							
		V _{CC} = 0.8 V	-	89.4	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	5.2	10.6	23.8	4.6	26.7	29.5	ns
		V _{CC} = 1.4 V to 1.6 V	4.0	7.3	13.2	3.0	15.7	17.4	ns
		V _{CC} = 1.65 V to 1.95 V	3.0	6.0	10.2	2.7	12.3	13.6	ns
		V_{CC} = 2.3 V to 2.7 V	2.8	5.0	7.8	2.6	9.3	10.3	ns
		V _{CC} = 3.0 V to 3.6 V	2.8	4.8	7.1	2.6	8.4	9.3	ns
t _{dis}	disable time	$n\overline{OE}$ to nY; see <u>Fig. 7</u> [4]							
		V _{CC} = 0.8 V	-	68.9	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	6.0	9.3	15.0	4.6	16.5	18.2	ns
		V _{CC} = 1.4 V to 1.6 V	4.4	7.7	11.0	3.0	12.2	13.4	ns
		V _{CC} = 1.65 V to 1.95 V	5.1	8.8	12.4	2.7	13.7	15.1	ns
		V_{CC} = 2.3 V to 2.7 V	3.6	6.2	9.0	2.6	10.0	11.0	ns
		V _{CC} = 3.0 V to 3.6 V	5.2	8.8	12.7	2.6	14.0	15.4	ns
C _L = 5 p	F, 10 pF, 15 pF	and 30 pF							
C _{PD}	power dissipation capacitance	$f = 1 \text{ MHz}; V_I = GND \text{ to } V_{CC}$ [5]							
		V _{CC} = 0.8 V	-	2.7	-	-	-	-	pF
		V _{CC} = 1.1 V to 1.3 V	-	2.9	-	-	-	-	pF
		V _{CC} = 1.4 V to 1.6 V	-	3.0	-	-	-	-	pF
		V _{CC} = 1.65 V to 1.95 V	-	3.2	-	-	-	-	pF
		V_{CC} = 2.3 V to 2.7 V	-	3.7	-	-	-	-	pF
		V _{CC} = 3.0 V to 3.6 V	-	4.2	-	-	-	-	pF

Low-power dual inverting buffer/line driver; 3-state

All typical values are measured at nominal V_{CC}. [1]

[2] [3]

[4] [5]

All typical values are measured at nominal V_{CC}. t_{pd} is the same as t_{PLH} and t_{PHL} . t_{en} is the same as t_{PZH} and t_{PZL} . t_{dis} is the same as t_{PHZ} and t_{PLZ} . C_{PD} is used to determine the dynamic power dissipation (P_D in µW). $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$ where: $f_i = input$ frequency in MHz;

f_o = output frequency in MHz;

C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.

Vм

outputs disabled

outputs enabled

mna961

11.1. Waveforms and test circuit

VOH

GND

outputs enabled

 V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

output HIGH-to-OFF

OFF-to-HIGH

Measurement points are given in Table 9.

3-state enable and disable times

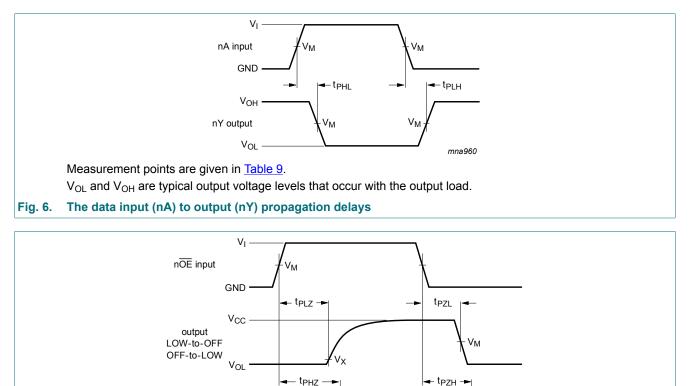


Table 9. Measurement points

Fig. 7.

Supply voltage	Input	Input			Output			
V _{cc}	V _M	VI	$t_r = t_f$	V _M	Vx	VY		
0.8 V to 1.6 V	$0.5 \times V_{CC}$	V _{CC}	≤ 3.0 ns	0.5 × V _{CC}	V _{OL} + 0.1 V	V _{OH} - 0.1 V		
1.65 V to 2.7 V	0.5 × V _{CC}	V _{CC}	≤ 3.0 ns	0.5 × V _{CC}	V _{OL} + 0.15 V	V _{OH} - 0.15 V		
3.0 V to 3.6 V	$0.5 \times V_{CC}$	V _{CC}	≤ 3.0 ns	0.5 × V _{CC}	V _{OL} + 0.3 V	V _{OH} - 0.3 V		

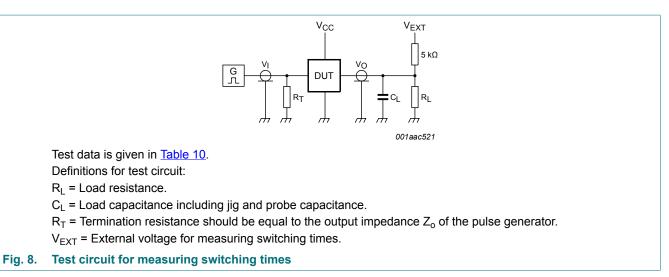


Table 10. Test data

Supply voltage	Load	V _{EXT}			
V _{CC}	CL	R _L [1]	t _{PLH} , t _{PHL}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}
0.8 V to 3.6 V	5 pF, 10 pF, 15 pF and 30 pF	5 k Ω or 1 M Ω	open	GND	2 × V _{CC}

[1] For measuring enable and disable times $R_L = 5 k\Omega$.

For measuring propagation delays, setup and hold times and pulse width R_L = 1 M Ω .

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12. Package outline

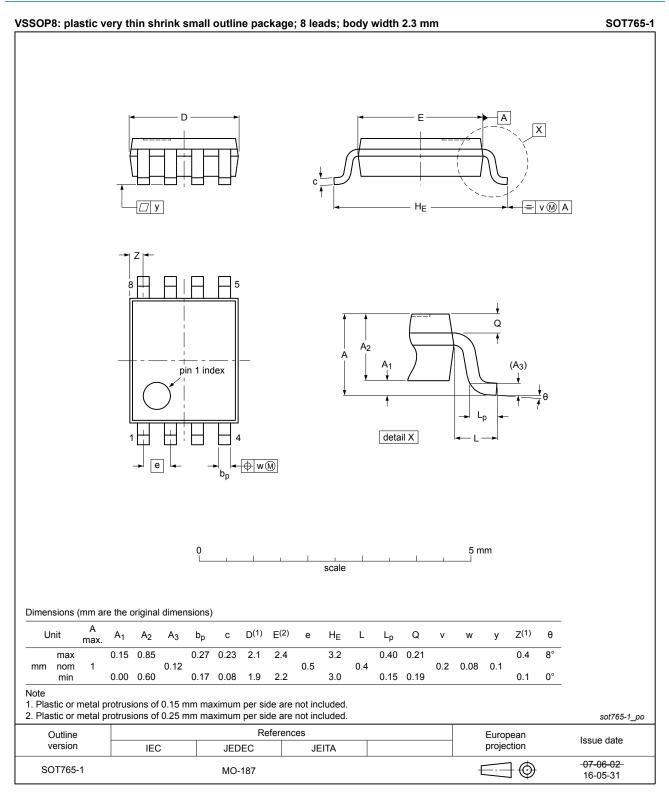


Fig. 9. Package outline SOT765-1 (VSSOP8)

Low-power dual inverting buffer/line driver; 3-state

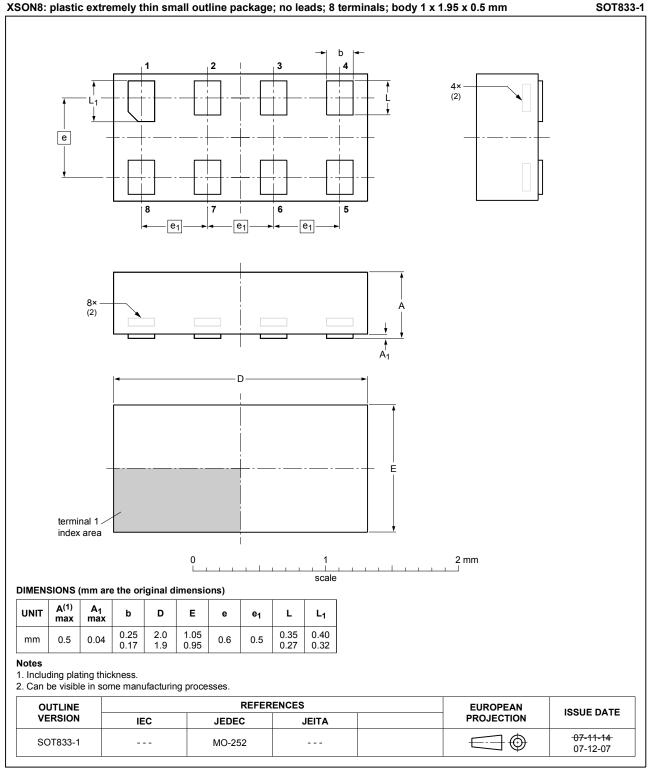


Fig. 10. Package outline SOT833-1 (XSON8)

Low-power dual inverting buffer/line driver; 3-state

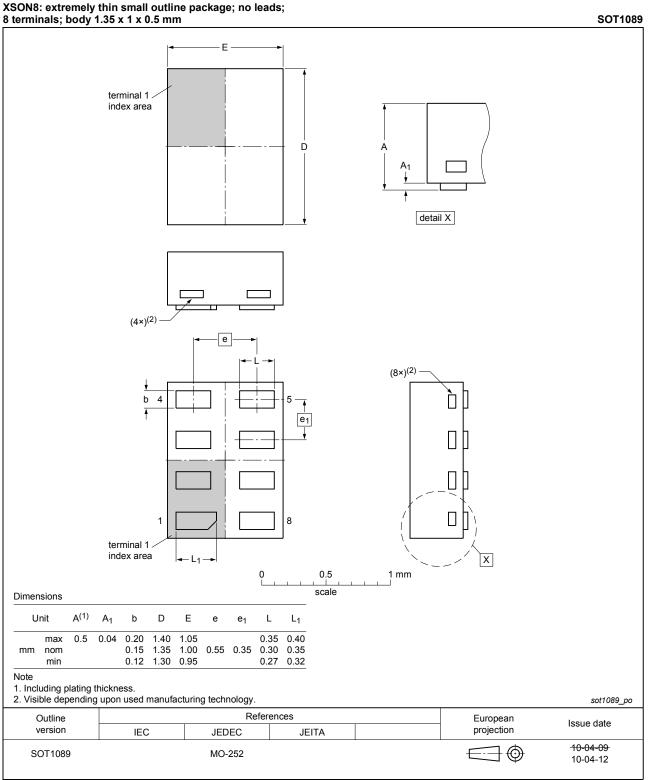
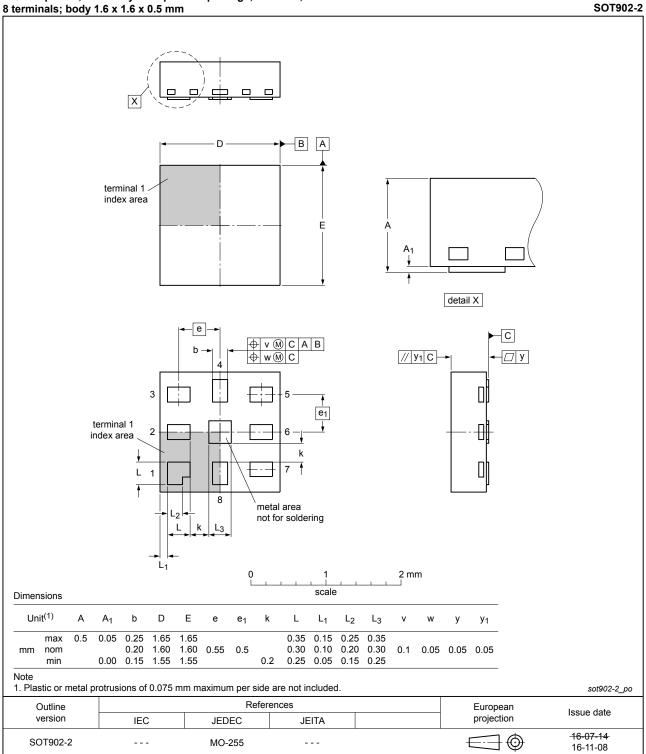


Fig. 11. Package outline SOT1089 (XSON8)

Low-power dual inverting buffer/line driver; 3-state

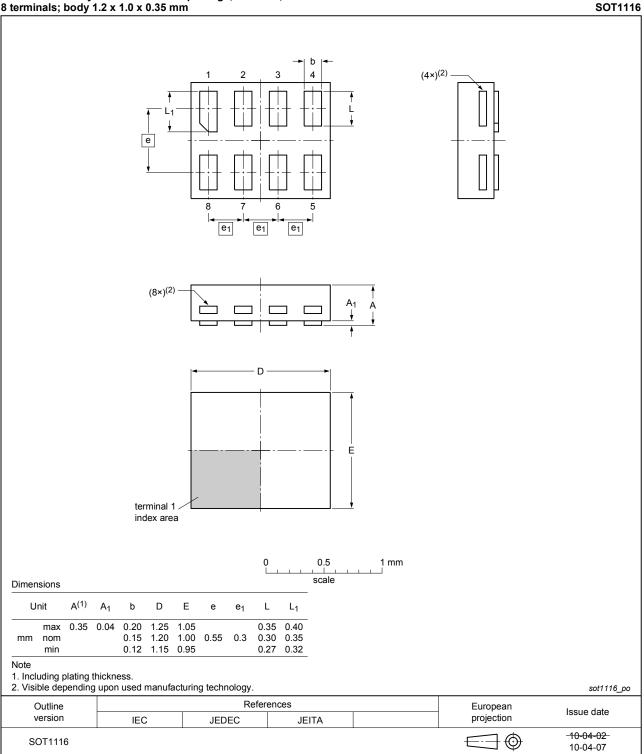


XQFN8: plastic, extremely thin quad flat package; no leads;

Fig. 12. Package outline SOT902-2 (XQFN8)

Low-power dual inverting buffer/line driver; 3-state

XSON8: extremely thin small outline package; no leads; 8 terminals; body 1.2 x 1.0 x 0.35 mm





Low-power dual inverting buffer/line driver; 3-state

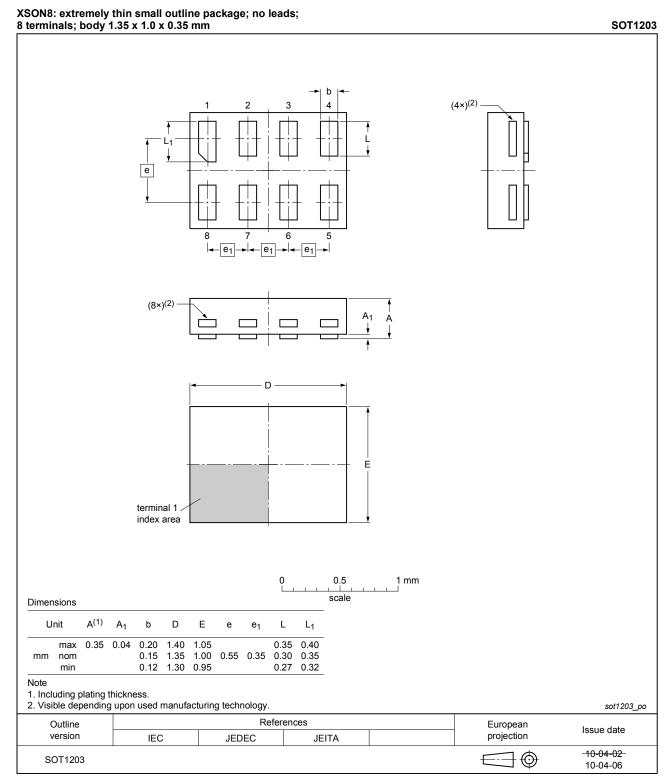


Fig. 14. Package outline SOT1203 (XSON8)

13. Abbreviations

Table 11. Abbreviations					
Acronym	Description				
CDM	Charged Device Model				
DUT	Device Under Test				
ESD	ElectroStatic Discharge				
НВМ	Human Body Model				
MM	Machine Model				

14. Revision history

Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes				
74AUP2G240 v.9	20190319	Product data sheet	-	74AUP2G240 v.8				
Modifications:	of Nexperia. • Legal texts h • Type numbe • Package out	Legal texts have been adapted to the new company name where appropriate.						
74AUP2G240 v.8	20130124	Product data sheet	-	74AUP2G240 v.7				
Modifications:	For type nun	For type number 74AUP2G240GD XSON8U has changed to XSON8.						
74AUP2G240 v.7	20120606	Product data sheet	-	74AUP2G240 v.6				
74AUP2G240 v.6	20111205	Product data sheet	-	74AUP2G240 v.5				
74AUP2G240 v.5	20100913	Product data sheet	-	74AUP2G240 v.4				
74AUP2G240 v.4	20090630	Product data sheet	-	74AUP2G240 v.3				
74AUP2G240 v.3	20090407	Product data sheet	-	74AUP2G240 v.2				
74AUP2G240 v.2	20080222	Product data sheet	-	74AUP2G240 v.1				
74AUP2G240 v.1	20061006	Product data sheet	-	-				

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

 Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at <u>https://www.nexperia.com</u>.

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